	Specification	Symb	ol Condition	/ Comment		HTS	201-20-GSM	241-20-GSM	301-20-GSM	Unit	
	Maximum Operating Voltage	V <sub>O(max</sub>	) l <sub>off</sub> < 50 μAD	C, T <sub>case</sub> = 70°	С		± 20000	± 24000	± 30000	VDC	
	Maximum Isolation Voltage	VI				), continuously		± 40000		VDC	
	U	ximum Isolation Voltage V <sub>I</sub> Between HV switch and control / GND, continuously x. Housing Insulation Voltage V <sub>INS</sub> Between switch and housing surface, 3 minutes					± 50000		VDC		
RATINGS	Maximum Turn-On Peak Cur	•		$T_{\text{case}} = 25^{\circ}\text{C}$ $t_p < 200 \mu\text{s}$ , duty cycle <1%				200			
	maximum rum-on reak cunent		Toase - 20 O					118			
Ĭ				t <sub>p</sub> < 1 ms, duty cycle <1% t <sub>p</sub> < 10 ms, duty cycle <1%				72			
					s, duty cycle			54		ADC	
5		irrent I <sub>L(max)</sub>		1 '						ADC	
MAXIMUM	Maximum Continuous Load Current			Standard devices & FC, forced air 4 m/s				1.7			
Š			T <sub>case</sub> = 25°					2.7			
Ž				Devices with option DLC		28.1			ADC		
इं	Max. Continuous Power Dissipa	ation Pd(max	)	Standard of	devices & F	C, forced air 4 m/s	15	17	20		
			T <sub>case</sub> = 25°	Devices w	ith option C	F, forced air 4 m/s	240	260	300		
				Devices w	ith option D	LC	2500	3000	3800	Wat	
2	Linear Derating			Standard of	devices & F	C, forced air 4 m/s	0.285	0.343	0.429		
S			Above 25°C			F, forced air 4 m/s	4.56	5.488	6.864		
<b>ABSOLUTE</b>			715070 25 0	Devices w			47.5	60.53	81.51	W/K	
•	Operating Temperature Dep	70 T-	Ctandard day				47.3		01.31	°C	
	Operating Temperature Range					LC. (Option DLC)		-4070 (60)		_	
	Storage Temperature Range T			Switches with option ILC may require frost protection!  Homogeneous steady-field, surrounding the whole switch			-50100		°C		
	Max. Permissible Magnetic Field E							25		mT	
	Max. Auxilliary Voltage Vaux		Protection by	Protection by built-in overvoltage limiter (replaceable)			5.5		VDC		
	Permissible Operating Voltage Vo		Unipolar ope	Unipolar operation (one switch pole grounded or floated)			0 ± 20000	0 ± 24000	0 ± 30000	VDC	
	Range		Bipolar oper	tion (positive & negative voltage applied)		0 ± 10000	0 ± 12000	0 ± 15000			
	Typical Breakdown Voltage		NOTE: V <sub>br</sub> is a	NOTE: V <sub>hr</sub> is a test parameter for quality control		ontrol . O. F A	22000	26000	32000	VDC	
	,,		purposes only.	purposes only. Not applicable in normal operation 0.8xVo, T <sub>case</sub> =2570°C, reduced loff on		ation! loff > 0.5 IIIA	22000		32000		
	Typical Off-State Current Ion		-					< 20		μAD	
	Typical Turn-On Resistance		Each switch	Each switching path		nax), T <sub>case</sub> =25°C	3.8	4.5	6.3		
			$t_p < 1 \mu s$ , dut	y cycle < 1%	1.0 x l <sub>P(r</sub>	nax), T <sub>case</sub> =25°C	8.5	10.2	14.3	Ohn	
	Typical Capacitive Power	P <sub>dc</sub>	Switch cana	citance only -	0.8 x V <sub>O</sub>	,.	0.243	0.313	0.432	1	
	Dissipation of Switch			nal load and		(max), f = 100 Hz	2.43	3.13	4.32		
	(Natural Power Dissipation)					(max), f = 1000 Hz	24.3	31.1	43.2		
	(Natural Power Dissipation)		ραιασιίο σαρ	parasitic capacitances			243	313	432	Wat	
•	Typical Propagation Dalay Time t		Desistive les	0.8 x V <sub>O(max)</sub> , f = 10000 Hz stive load, 0.1 x I <sub>P(max)</sub> , 0.8 x V <sub>O(max)</sub> , 50-50%		240	200	402	_		
્	Typical Propagation Delay Time t									ns	
2	Typical Output Pulse Jitter t <sub>j</sub>		Impedance matched input, Va					3		ns	
Ž	Typical Ouput Transition Time (Rise Time & Fall Time)		Resistive loa	d, 10-90%		$I_{l(max)}$ , $I_{L} = 0.1 \times I_{p(max)}$	10	11	11		
7				$0.8 \times V_{O(max)}, I_L = 0.1 \times I_{p(max)}$			26	27	30		
Ş					0.8 x Vc	$I_{(max)}$ , $I_{L} = 1.0 \text{ x } I_{p(max)}$	30	32	33	ns	
Š	Maximum Turn-On Time ton(		No limitation				∞		ns		
CHARACTERISTICS	Minimum Turn-On Time ton(min)		can be custo	can be customized. Please consult factory				200		ns	
9	Max. Continuous Switching   t <sub>(max)</sub>		@ V <sub>aux</sub> = 5.0	@ V <sub>aux</sub> = 5.00 V   Standard devices without HFS option				1.7			
4	Frequency		Sw. shutdow	Sw. shutdown if Standard devices with HFS supply				100			
	. ,		f <sub>(max)</sub> is exceeded Opt. HFS + sufficient cooling option				200		kHz		
ECTRICAL	Maximum Burst Frequency f <sub>b(</sub>			Use option HFB for >10 pulses within 20µs or less			2			MH:	
EC	Maximum Number of Pulses / Burst			f <sub>b=1</sub> MHz (1μs spacing). Switch shutdown if N <sub>(max)</sub> is exceeded.				st option HFB for >200 pulse			
EL	Coupling Capacitance					options CF, DLC	14	17	21	s i uist	
	Coupling Capacitance	Cc									
			control side			GCF, ILC	105	130	160	pF	
	Natural Capacitance	C <sub>N</sub>		tch poles, @ 0			65	55	45	pF	
	Control Voltage Range	V <sub>ctrl</sub>		s no impact on		· · · · · · · · · · · · · · · · · · ·		2 6		VDC	
	Auxiliary Supply Voltage Range V			pply is not requ		HFS mode.		4.5 5.5		VDC	
	Typical Auxiliary Supply Curr	ent laux	V <sub>aux</sub> = 5.00 \	/DC, T <sub>case</sub> = 25	°C.	0.01 x f <sub>(max)</sub>		250			
				limitation above		@ specified f(max)		500		mAD	
	Opt. HFS, Ext. Supply Voltage	je V1 V <sub>HFS(\</sub>	Stability ±3%	6, current cons	umption <	2 mA/kHz @ 25°C		15		VDC	
	Opt. HFS, Ext. Supply Voltage					12 mA/kHz @ 25°C	210	220	230	VDC	
	Intrinsic Diode Forward Voltage			, I <sub>F</sub> = 0.3 x I <sub>P(m</sub>		, 12 0 20 0	17	20	25	VDC	
	Diode Reverse Recovery Time				,	100 1/40	17	<250	20	-	
	•			, I <sub>F</sub> = 0.3 x I <sub>P(m</sub>		του Αγμδ	005-450-50		075-450-50	ns	
	Dimensions	LxWx		using, without	pigialis		225x150x58	250x150x58	275x150x58		
Ş			Devices with option CF				225x150x58 275x200x68	250x150x58	275x150x58		
HOUSING			Devices with option ILC & DLC				300x200x68	325x200x68	mm		
2	Weight		Standard housing					<2650			
ž		Devices with	Devices with option CF Devices with option ILC & DLC				<3800				
		Devices with					<3200		g		
	Control Signal Input P	in 1 / Yellow (	S-C: Pin 1). TT	TTL compatible (LS-C: With 100Ω termination). Schmitt-Trigger characteristics. Control voltage 2-10 V (3-5 V for low jitter)							
										,	
2				Shielding). The ground pin is internally connected with the safety earthings terminals (threaded inserts) on bottom side.  1 4). The 5 V input is used for rep rates up to the specified max. frequency f <sub>(max)</sub> . Higher rep rates require option HFS.							
5									•		
	Fault Signal Output  Pin 4 / Orange (LS-C: Pin 3). TTL output, short circuit proof. Indicating switch &									t.	
FUNCTIONS	Inhibit Signal Input Pin 5 / Green (LS-C: Pin 2). TTL compatible, Schmitt-Trigger characteristics for						or the connection of	external safety circuits. L	. = Switch Inhibited.		
	LED Indicators GREEN: "Switching path B ON". YELLOW: "Switching pa					oath A ON". RED: "F	ault condition or inf	nibit input "L", switch OFF	="		
		• .	<u>.</u>				response time < 60 s @ 3xPd(max), $\Delta$ T=25K (50 to 75°C). Separate driver				
	· ·		•								
	protection. B) Switches with option DLC: 65°C, response time < 3 s @ 3xPo								· · · · · · · · · · · · · · · · · · ·	and the state of	
			Option LP Low Pass. Input filter for increased noise immunity.  Option HER High Frequency Burst (improved capability by external capacit				Option Min-On Individually increased "Minimum On-Time" to avoid unwanted triggerin ors) Option Min-Off Individually increased "Minimum Off-Time" to avoid unwanted triggerin				
×	HTS 241-20-GSM Fast HV Transistor HTS 301-20-GSM Fast HV Transistor			Option HFB High Frequency Burst (improved capability by external capacit				Soft Transition Time decrease the		neu triggerii	
Ä	rasi nv iransistor	OWILLII, OUKV, 2007		Option HFS High Frequency Switching (two auxiliary supply inputs V			Option S-11	Integrated Freewheeling Diode N			
								, ,			
8					Option CF Copper Cooling Fins. P <sub>d(max)</sub> can be increased by the factor 3 to Option ILC Indirect Liquid Cooling (for water). P <sub>d(max)</sub> can be increased by the factor						
ORDER								+			